VS-VSUD360CW40

Vishay Semiconductors



FRED Pt[®] Ultrafast Soft Recovery Diode Module, 360 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	360 A				
V _R	400 V				
Q _{rr} (typical)	243 nC				
t _{rr}	74 ns				
Туре	Modules - diode, FRED Pt [®]				
Package	TO-244				
Circuit configuration	Two diodes common cathode				

FEATURES

- Very low Q_{rr} and t_{rr}
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing

DESCRIPTION / APPLICATIONS

FRED Pt[®] diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are a significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
		T _C = 25 °C	510		
Continuous forward current per diode	I _{F(AV)}	T _C = 85 °C	305	А	
			T _C = 116 °C	180	A
Single pulse forward current per diode	I _{FSM}	T _C = 25 °C	2880		
Maximum power dissipation	PD	T _C = 25 °C	570	W	
Maximum power dissipation	FD	T _C = 110 °C	180	vv	
Operating junction and storage temperatures	T _J , T _{Stg}		-40 to +150	°C	

ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MA		MAX.	UNITS	
Breakdown voltage	V _{BR}	I _R = 100 μA		-	-	
		I _F = 180 A	-	1.09	1.27	
Forward valtage	V	I _F = 360 A	-	1.23	1.50	V
Forward voltage	V _{FM}	I _F = 180 A, T _J = 150 °C	-	0.88	0.96	
		I _F = 360 A, T _J = 150 °C	-	1.04	1.18	
Reverse leakage current	I _{RM}	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$		0.26	1.28	mA
Series inductance	L _S	From top of terminal hole to mounting plane - 5 -		nH		

 Revision: 14-Dec-2018
 1
 Document Number: 93116

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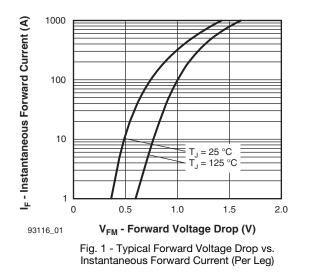


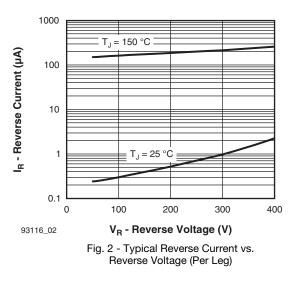


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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
	I _F = 1.0 A, dI _F /dt = 200 A/μs, V _R = 30 V		/μs, V _R = 30 V	-	40	69	
Reverse recovery time	Reverse recovery time t _{rr}	T _J = 25 °C	I _F = 180 A, dI _F /dt = 200 A/μs,	-	74	-	ns
		T _J = 150 °C	$V_{\rm R} = 200 \text{ V}$	-	171	-	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	5.1	-	
Peak recovery current I _{RRM}	I _F = 180 A, dI _F /dt = 200 A/μs, V _R = 200 V		-	6.6	-	А	
		I_F = 180 A, dI_F/dt = 200 A/µs, V_R = 200 V, T_J = 150 $^\circ C$		-	15.2	-	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	125	-	
Reverse recovery charge	Q _{rr}	$I_F = 180 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 200 \text{ V}$		-	243	-	nC
			I _F = 180 A, dI _F /dt = 200 A/µs, V _R = 200 V, T _J = 150 °C		1295	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case per leg	P		-	-	0.19	
Thermal resistance, junction-to-case per module	R _{thJC}		-	-	0.095	°C/W
Thermal resistance, case-to-heatsink (flag greased surface)	R _{thCS}		-	0.10	-	
Weight			-	68	-	g
Weight			-	2.4	-	oz.
Mounting torque			30 (3.4)	-	40 (4.6)	المح الم
Mounting torque center hole			12 (1.4)	-	18 (2.1)	lbf · in (N · m)
Terminal torque			30 (3.4)	-	40 (4.6)	(11 * 11)
Vertical pull			-	-	80	11. C
2" lever pull			-	-	35	lbf ∙ in
Case style			TO-244			





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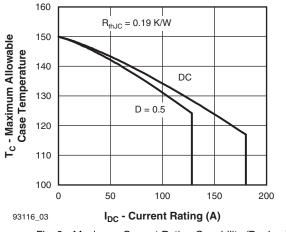
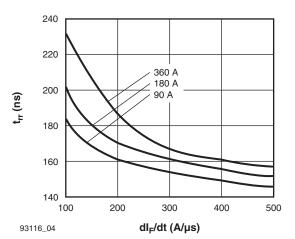
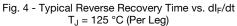


Fig. 3 - Maximum Current Rating Capability (Per Leg)



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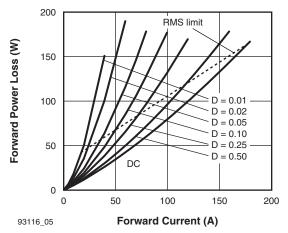


Fig. 5 - Forward Power Loss Characteristics

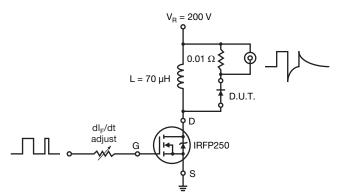
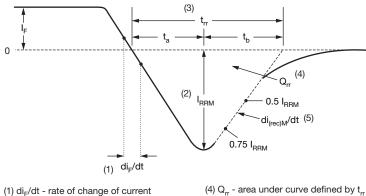


Fig. 6 - Reverse Recovery Parameter Test Circuit

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through zero crossing

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current. $Q_{rr} = \frac{t_{rr} \times l_{RRM}}{2}$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 7 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	vs-vs	UD	360	С	W	40	
	1	2	3	4	5	6	
	1 -		ay Semi			~	
	2 -	Туре	of devi	ce: UD =	= FRED	Pt [®]	
	3 - Current rating (360 = 360 A)						
	4 - Circuit configuration:						
		C = t	wo diod	es comi	non cat	hode	
	5 -	Туре	of devi	ce:			
		W =	TO-244	wire bo	ndable	not insula	ated
	6 -	Volta	ige ratin	g (40 =	400 V)		

CIRCUIT CONFIGURATION				
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Two diodes common cathode	С	Lug terminal o anode 2 Lug terminal o anode 1		

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95021	

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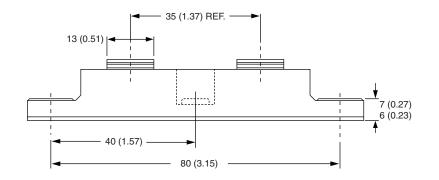


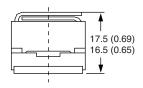


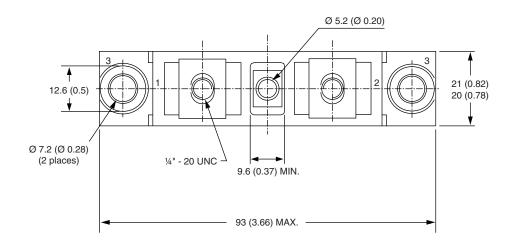
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TO-244

DIMENSIONS in millimeters (inches)









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